

Sol^m to HA #4

1 $V_E = -1V \Rightarrow I_E = \frac{V_E - (-5)}{4K} = \frac{1mA}{4K}$, $V_{BE} = 0.7V \Rightarrow V_B = V_E + V_{BE} = -1 + 0.7 = -0.3V \Rightarrow I_B = \frac{0 - (-0.3)}{60K} = 5\mu A$, $I_C = I_E - I_B = 1mA - 5\mu A = 0.995mA$, $V_C = +5 - I_C \times 3K = 5 - 0.995 \times 3 = 2.015V \Rightarrow V_{CE} = V_C - V_E = 2.015 - (-1) = 3.015V$, $\beta = \frac{I_C}{I_B} = \frac{0.995mA}{5\mu A} = 199$, $\alpha = \frac{\beta}{\beta+1} = \frac{199}{199+1} = 0.995 = \frac{I_C}{I_E}$.

Power drawn from $\pm 5V$ supplies $P_{drawn} = +5V \times I_C + |-5V| \times I_E$

$\Rightarrow P_{drawn} = 5 \times 0.995 + 5 \times 1 = 9.975mW$

Power dissipated in the transistor, $P_Q = V_{CE} \times I_C = 3.015 \times 0.995 = 3mW$

" " " 60K resistor, $P_{60K} = I_B^2 \times 60K = (5\mu A)^2 \times 60K = 1.5\mu W$

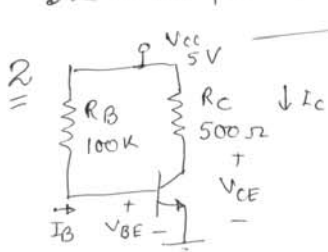
" " " 3K " , $P_{3K} = I_C^2 \times 3K = (0.995mA)^2 \times 3K = 2.97mW$

" " " 4K " , $P_{4K} = I_E^2 \times 4K = (1mA)^2 \times 4K = 4mW$

\Rightarrow Total power dissipated, $P_{dissipated} = P_Q + P_{60K} + P_{3K} + P_{4K} = 9.97mW$

\Rightarrow Total power drawn = total power dissipated \Rightarrow Conserved quantity.

Due to the principle of conservation of total energy.



Nominal $\beta = 100 \Rightarrow I_B = \frac{V_{CC} - V_{BE}}{R_B} = \frac{5 - 0.7}{100K} = 43\mu A$.

Note that this current is independent of β .

$I_C = \beta I_B = 4.3mA$ (nominal), $V_{CE} = V_{CC} - I_C R_C = 2.85V$ (nominal)

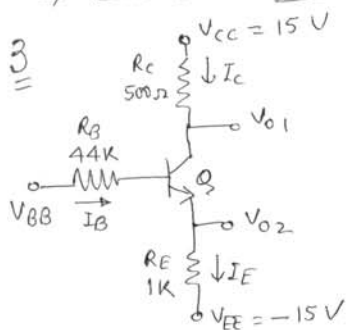
$\beta = 50\% \Rightarrow I_C = 2.15mA \Rightarrow \% \text{ change} = -50\%$ (same as β)

$V_{CE} = 3.925V \Rightarrow \% \text{ change} = +37.72\%$

$\beta = 150\% \Rightarrow I_C = 6.45mA \Rightarrow \% \text{ change} = +50\%$, $V_{CE} = 1.775V \Rightarrow \% \text{ change} = -37.72\%$

Thus, there is a large change in I_C & V_{CE} with respect to β variation

\Rightarrow The ckt. is not robust at all.



a) i) $V_{BB} = 0$: Writing KVL in the BE loop of Q:

$I_B R_B + V_{BE} + I_E R_E + V_{EE} = 0$ Also, $I_E = (\beta+1)I_B$

$\Rightarrow I_B = \frac{-V_{BE} - V_{EE}}{R_B + (\beta+1)R_E} = \frac{-0.7 + 15}{44K + 101 \times 1K} = 98.62\mu A$

$I_C = \beta I_B = 9.86mA$ & $I_E = (\beta+1)I_B = 9.96mA$

$V_{01} = V_{CC} - I_C R_C = 15 - 9.86 \times 0.5 = 10.07V$

$V_{02} = V_{EE} + I_E R_E = -15 + 9.96 \times 1 = -5.04V$

Note: $V_{CE} = V_C - V_E = 15.11V \Rightarrow$ forward active

ii) With $V_{O1} = 0$, $V_{CE} = 5.04V \Rightarrow$ Thus, the transistor would remain in the forward active mode. $\therefore I_C$ would remain independent of R_C , & for $V_{O1} = 0$, $I_C R_C$ must equal V_{CC} , which gives $R_C = \frac{V_{CC}}{I_C} = \frac{15V}{9.86mA} = 1.52K$. (2)

b) i) At onset of saturation: $V_{BE} = 0.7V$ & $V_{CE} = 0.7V$ (with $V_{BC} = 0$)
At this point, β & α would retain their nominal midband values.

Writing KVL at the output ckt:

$$V_{CC} - V_{CE} - V_{EE} = I_C R_C + I_E R_E \quad \& \quad I_E = \frac{I_C}{\alpha} \Rightarrow V_{CC} - V_{CE} - V_{EE} = I_C (R_C + \frac{R_E}{\alpha})$$

$$\text{with } \beta = 100 \quad \alpha = \frac{\beta}{\beta+1} = \frac{100}{101} = 0.99$$

$$\Rightarrow I_C = \frac{15 - 0.7 + 15}{500 + 1000/0.99} = 19.4mA \Rightarrow I_B = \frac{I_C}{\beta} = 194\mu A \quad \& \quad I_E = \frac{I_C}{\alpha} = 19.6mA$$

$$\therefore V_{BB} = I_B R_B + V_{BE} + I_E R_E + V_{EE} = 194\mu A \times 44K + 0.7 + 19.6mA \times 1K - 15 = 13.84V$$

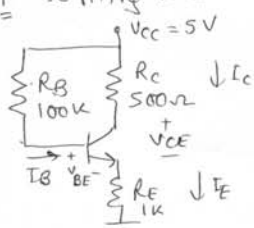
ii) $\beta_{sat} = 10 \Rightarrow Q$ in hard saturation with $V_{BE} = 0.8V$ & $V_{CE} = 0.1V$, also $\alpha = \frac{10}{11} = 0.909$

$$\text{For this case, } I_C = \frac{15 - 0.1 + 15}{500 + 1000/0.909} = 18.7mA$$

$$\text{which gives } I_E = \frac{I_C}{\alpha} = 20.56mA \quad \& \quad I_B = \frac{I_E}{\beta+1} = 1.87mA$$

$$\therefore V_{BB} = 1.87mA \times 44K + 0.8 + 20.56mA \times 1K - 15 = 88.64V \quad (\text{Very large!})$$

4 Writing KVL in the BE loop: $V_{CC} = I_B R_B + V_{BE} + I_E R_E$ with $I_E = (\beta+1)I_B$



$$\Rightarrow I_B = \frac{V_{CC} - V_{BE}}{R_B + (\beta+1)R_E} = 21.4\mu A \quad (\beta=100, \text{nominal}), \quad 28.4\mu A \quad (\beta=50), \quad \text{and } 17.13\mu A \quad (\beta=150)$$

$$\Rightarrow I_C = \beta I_B = 2.14mA \quad (\beta=100), \quad 1.424mA \quad (\beta=50), \quad \& \quad 2.57mA \quad (\beta=150)$$

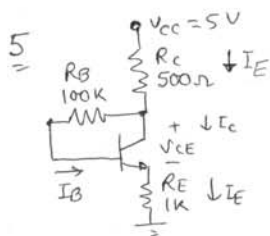
$$\% \text{ change in } I_C = -33.46\% \quad (\beta=50), \quad \& \quad +20.09\% \quad (\beta=150)$$

$$I_E = I_C + I_B = 2.16mA \quad (\beta=100), \quad 1.45mA \quad (\beta=50), \quad \& \quad 2.59mA \quad (\beta=150)$$

$$\therefore V_{CE} = V_{CC} - I_C R_C - I_E R_E = 1.77V \quad (\beta=100), \quad 2.84V \quad (\beta=50), \quad \& \quad 1.125V \quad (\beta=150)$$

$$\% \text{ change in } V_{CE} = +60.45\% \quad (\beta=50), \quad \& \quad -36.44\% \quad (\beta=150)$$

$\Rightarrow \% \text{ change in } I_C$ decreased, but that of V_{CE} increased a bit. (as compared to Prob. 2)



Note: Current than $R_C = I_C + I_B = I_E \Rightarrow$ KVL $\Rightarrow V_{CC} = I_E R_C + I_B R_B + V_{BE} + I_E R_E$

$$\Rightarrow I_B = \frac{V_{CC} - V_{BE}}{R_B + (\beta+1)(R_C + R_E)} = 17.1\mu A \quad (\beta=100, \text{nominal}), \quad 24.36\mu A \quad (\beta=50), \quad \& \quad 13.17\mu A \quad (\beta=150)$$

$$\Rightarrow I_C = \beta I_B = 1.71mA \quad (\beta=100), \quad 1.218mA \quad (\beta=50), \quad 1.976mA \quad (\beta=150)$$

$$\% \text{ change in } I_C = -28.77\% \quad (\beta=50), \quad \& \quad +15.56\% \quad (\beta=150)$$

$$I_E = I_C + I_B = 1.727mA \quad (\beta=100), \quad 1.242mA \quad (\beta=50), \quad \& \quad 1.989mA \quad (\beta=150)$$

$$V_{CE} = V_{CC} - I_E (R_C + R_E) = 2.41V \quad (\beta=100), \quad 3.137V \quad (\beta=50), \quad \& \quad 2.017V \quad (\beta=150)$$

$$\% \text{ change in } V_{CE} = +30.17\% \quad (\beta=50), \quad \& \quad -16.31\% \quad (\beta=150). \quad \text{Performance improved, but not that much!}$$